

3918590 GENERAL SEMICONDUCTOR

95D 02132 D



NPN SWITCHING POWER TRANSISTORS

This unique series utilizes General Semiconductor Industries' C²R[®] process which describes a manufacturing technology that provides surface stabilization for high voltage operation and enhances long term reliability.

7-33-07
NPN
225, 275, 325V
1.0 AMP SWITCHING

TO-66

| *MAXIMUM RATINGS (T _c = 25°C unless otherwise noted.) | | | | | |
|--|--|-------------|-------------|-------------|-------|
| RATING | SYMBOL | 2N6233 | 2N6234 | 2N6235 | UNIT |
| Collector-Base Voltage | V _{CBO} | 250 | 300 | 350 | Volts |
| Collector-Emitter Voltage | V _{CEO} | 225 | 275 | 325 | Volts |
| Emitter-Base Voltage | V _{EBO} | 6.0 | 6.0 | 6.0 | Volts |
| Collector Current—Continuous | I _c | 5.0 | 5.0 | 5.0 | Amps |
| Peak | I _{CM} | 10 | 10 | 10 | Amps |
| Base Current—Continuous | I _B | 2.0 | 2.0 | 2.0 | Amps |
| Total Power Dissipation @T _c = 25°C | P _D | 50 | 50 | 50 | Watts |
| Junction to Case Thermal Resistance | R _{θJC} | 3.5 | 3.5 | 3.5 | °C/W |
| Operating and Storage Junction Temperature Range | T _{J(oper)} T _{stg} | -65 to +200 | -65 to +200 | -65 to +200 | °C |

| *ELECTRICAL CHARACTERISTICS (T _c = 25°C unless otherwise noted) | | | | | | | | |
|--|---|--------|-----|--------|-----|--------|-----|-------|
| SYMBOL | CONDITIONS | 2N6233 | | 2N6234 | | 2N6235 | | Unit |
| | | Min | Max | Min | Max | Min | Max | |
| V _{CE(sat)} | I _c = 20mA | 225 | — | 275 | — | 325 | — | Volts |
| I _{CEX} | V _{BE} = -1.5V, T _c = 150°C | — | 1.0 | — | — | — | — | mA |
| | V _{CE} = 250V—2N6233 | — | — | — | 1.0 | — | — | |
| | V _{CE} = 300V—2N6234 V _{CE} = 350V—2N6235 | — | — | — | — | — | 1.0 | |
| I _{CBO} | V _{CB} = 225V—2N6233 | — | 0.1 | — | — | — | — | mA |
| | V _{CB} = 300V—2N6234 | — | — | — | 0.1 | — | — | |
| | V _{CB} = 350V—2N6235 | — | — | — | — | — | 0.1 | |
| I _{EBO} | V _{EB} = 6.0V | — | 0.1 | — | 0.1 | — | 0.1 | mA |
| I _{CEO} | V _{CE} = 225—2N6233 | — | 1.0 | — | — | — | — | mA |
| | V _{CE} = 275V—2N6234 | — | — | — | 1.0 | — | — | |
| | V _{CE} = 325V—2N6235 | — | — | — | — | — | 1.0 | |
| h _{FE} † | V _{CE} = 5.0V, I _c = 0.1A | 25 | — | 25 | — | 25 | — | |
| h _{FE} † | V _{CE} = 5.0V, I _c = 1.0A | 25 | 125 | 25 | 125 | 25 | 125 | |
| h _{FE} † | V _{CE} = 5.0V, I _c = 3.0A | 10 | — | 10 | — | 10 | — | |
| V _{CE(sat)} † | I _c = 5.0A, I _B = 1.0A | — | 2.5 | — | 2.5 | — | 2.5 | Volts |
| V _{CE(sat)} † | I _c = 1.0A, I _B = 0.1A | — | 0.5 | — | 0.5 | — | 0.5 | Volts |
| V _{BE(sat)} † | I _c = 5.0A, I _B = 1.0A | — | 2.0 | — | 2.0 | — | 2.0 | Volts |
| V _{BE(sat)} † | I _c = 1.0A, I _B = 0.1A | — | 1.0 | — | 1.0 | — | 1.0 | Volts |
| V _{BE(on)} † | V _{CE} = 5.0V, I _c = 1.0A | — | 1.0 | — | 1.0 | — | 1.0 | Volts |
| h _{FE} | V _{CE} = 10V, I _c = 0.25A, f = 10MHz | 2.0 | — | 2.0 | — | 2.0 | — | |
| C _{OBO} | V _{CB} = 10V, f = 0.1MHz | — | 250 | — | 250 | — | 250 | pF |
| SWITCHING | | | | | | | | |
| t _r | Resistive Load V _{CC} = 200V I _c = 1.0A I _{B1} = I _{B2} = 100mA t _p = 10μs | — | 0.5 | — | 0.5 | — | 0.5 | μs |
| t _s | | — | 3.5 | — | 3.5 | — | 3.5 | μs |
| t _f | | — | 0.5 | — | 0.5 | — | 0.5 | μs |
| | | | | | | | | |

*JEDEC registered data. † Pulse Conditions: Width = 300μs; Duty Cycle ≤ 2% (measured using Kelvin connections).